

RJK0630JPE

Silicon N Channel MOS FET High Speed Power Switching

R07DS0340EJ0100 Rev.1.00 Apr 18, 2011

Features

• For Automotive application

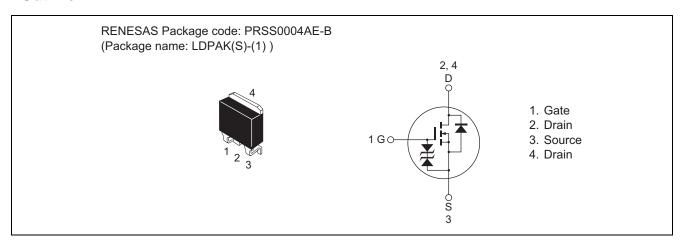
• AEC-Q101 compliant

• Low on-resistance : $R_{DS(on)} = 6.2 \text{ m}\Omega \text{ typ.}$

• Capable of 4.5 V gate drive

• Low input capacitance : Ciss = 2100 pF typ.

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

| Item | Symbol | Value | Unit |
|---|-------------------------------|-------------|------|
| Drain to source voltage | V _{DSS} | 60 | V |
| Gate to source voltage | V_{GSS} | ±20 | V |
| Drain current | I _D | 75 | Α |
| Drain peak current | I _D (pulse) Note1 | 300 | Α |
| Body-drain diode reverse drain current | I _{DR} | 75 | Α |
| Body-drain diode reverse drain peak current | I _{DR} (pulse) Note1 | 300 | Α |
| Avalanche current | I _{AP} Note2 | 35 | Α |
| Avalanche energy | E _{AR} Note2 | 105 | mJ |
| Channel dissipation | Pch Note3 | 85 | W |
| Channel temperature | Tch Note4 | 175 | °C |
| Storage temperature | Tstg | -55 to +150 | °C |

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Tch = 25°C, Rg \geq 50 Ω

3. $Tc = 25^{\circ}C$

4. AEC-Q101 compliant

Thermal Impedance Characteristics

• Channel to case thermal impedance θ ch-c: 1.76°C/W

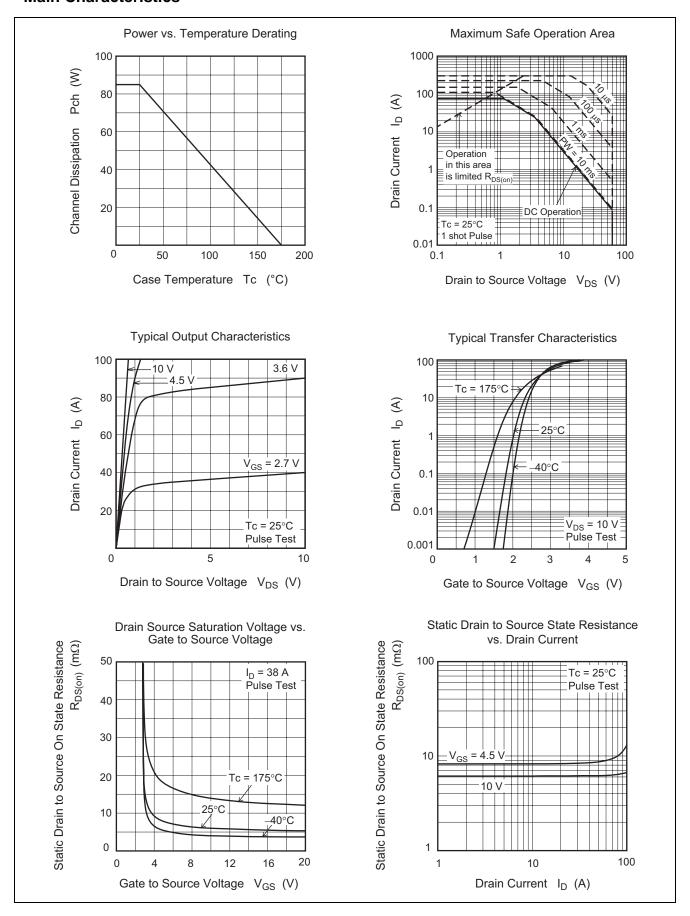
Electrical Characteristics

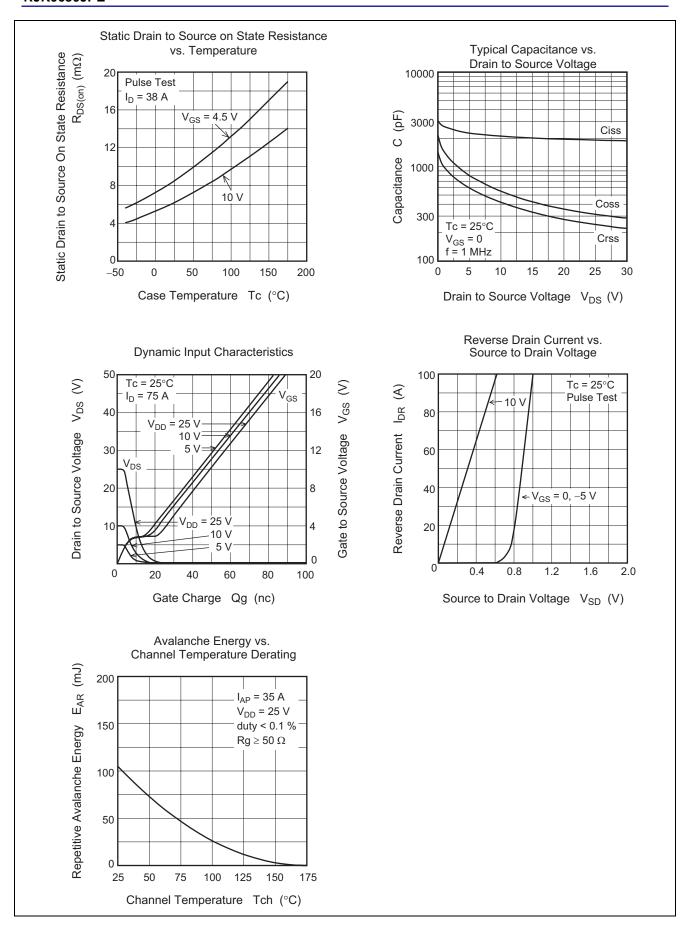
 $(Ta = 25^{\circ}C)$

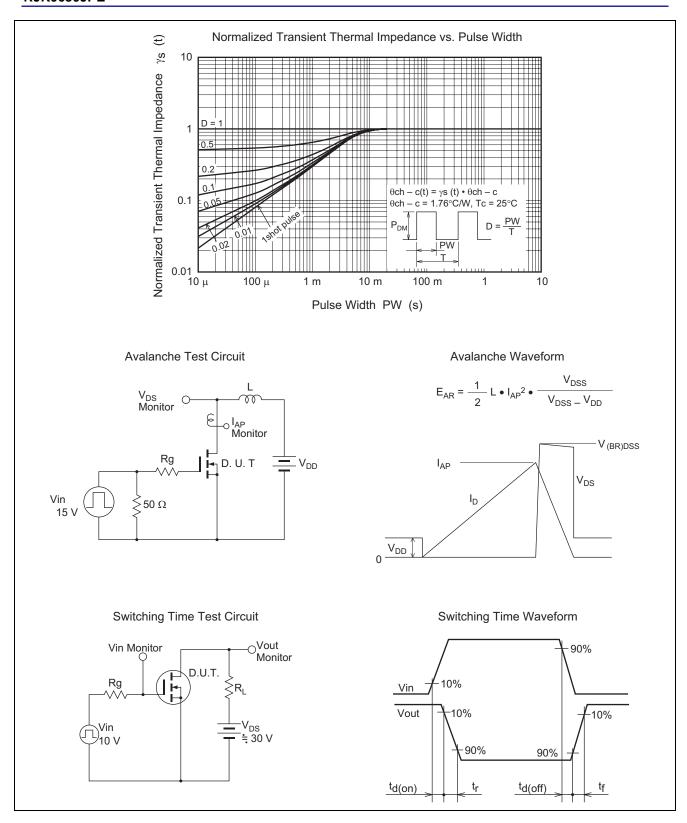
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
|-----------------------------------|---------------------|-----|------|------|------|---|
| Gate to source leak current | I _{GSS} | _ | _ | ±10 | μΑ | $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$ |
| Zero gate voltage drain current | I _{DSS} | _ | _ | 1 | μΑ | $V_{DS} = 60 \text{ V}, V_{GS} = 0$ |
| Gate to source cutoff voltage | $V_{GS(off)}$ | 1.0 | _ | 2.0 | V | $I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$ |
| Static drain to source on state | R _{DS(on)} | _ | 6.2 | 7.5 | mΩ | $I_D = 38 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note}5}$ |
| resistance | | _ | 8.5 | 11.5 | mΩ | $I_D = 38 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note5}}$ |
| Input capacitance | Ciss | _ | 2100 | _ | pF | $V_{DS} = 10 \text{ V}, V_{GS} = 0$ |
| Output capacitance | Coss | _ | 550 | _ | pF | f = 1 MHz |
| Reverse transfer capacitance | Crss | _ | 420 | _ | pF | |
| Total gate charge | Qg | _ | 49 | _ | nC | $V_{DD} = 10 \text{ V}, V_{GS} = 10 \text{ V},$ |
| Gate to source charge | Qgs | _ | 7 | _ | nC | $I_D = 75 \text{ A}$ |
| Gate to drain charge | Qgd | _ | 15 | _ | nC | 1 |
| Turn-on delay time | t _{d(on)} | _ | 16 | _ | ns | $I_D = 38 \text{ A}, R_L = 2.0 \Omega,$ |
| Rise time | t _r | _ | 17 | _ | ns | $V_{GS} = 10 \text{ V}, R_G = 4.7 \Omega$ |
| Turn-off delay time | t _{d(off)} | _ | 65 | _ | ns | |
| Fall time | t _f | _ | 18 | _ | ns | |
| Body-drain diode forward voltage | V_{DF} | _ | 0.94 | _ | V | $I_F = 75 \text{ A}, V_{GS} = 0^{\text{Note}5}$ |
| Body-drain diode reverse recovery | t _{rr} | _ | 45 | _ | ns | $I_F = 75 \text{ A}, V_{GS} = 0,$ |
| time | | | | | | di _F /dt = 100 A/μs |

Note: 5. Pulse test

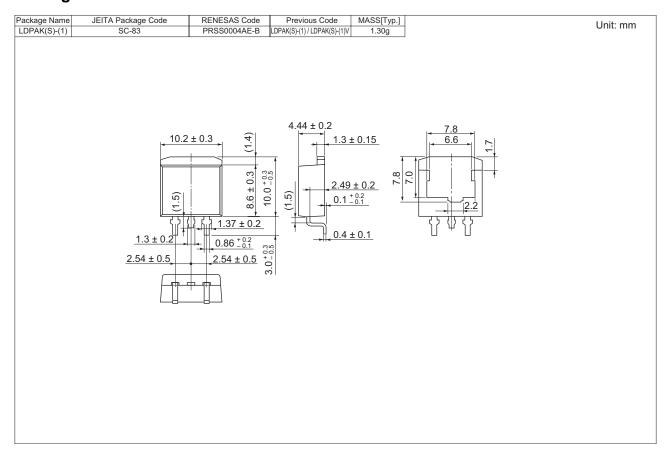
Main Characteristics







Package Dimensions



Ordering Information

| Orderable Part Number | Quantity | Shipping Container |
|-----------------------|----------|----------------------|
| RJK0630JPE-00-J3 | 1000 pcs | Taping (Sinistrorse) |

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